High Power PIN Diode 50 MHz - 18 GHz

Rev. V3

МАСОМ

Features

- 3 Terminal LPF Broadband Shunt Structure
- 50 MHz 18 GHz Broadband Frequency
- >100 W Peak Power Handling
- <0.1 dB Shunt Insertion Loss
- >23 dB Shunt Isolation
- <45°C/W Thermal Resistance
- Lead-Free 1.5 x 1.2 mm 6-lead TDFN Package
- RoHS* Compliant

Description

The MADP-011027 is a lead-free $1.5 \times 1.2 \text{ mm}$ TDFN surface mount plastic packaged that provides both low and high signal frequency operation from 50 MHz to 18 GHz. The higher breakdown voltage and lower thermal resistance of the PIN diode provides peak power handling in excess of 100 W.

This device is ideally suitable for usage in higher incident power switches, phase shifters, attenuators, and limiter microwave circuits over a broad frequency where higher performance surface mount diode assemblies are required.

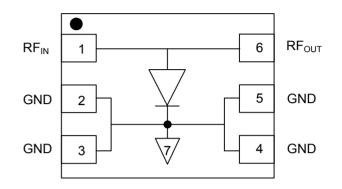
Ordering Information^{1,2}

Part Number	Package
MADP-011027-14150T	3000 piece reel
MADP-011027-000SMB	sample board

1. Reference Application Note M513 for reel size information.

2. All RF Sample boards include 5 loose parts.

Functional Schematic



Pin Configuration³

Pin No.	Pin Name Descriptio	
1	RF _{IN}	RF Input
2	GND	Ground
3	GND	Ground
4	GND	Ground
5	GND	Ground
6	RFout	RF Output
7	Paddle ⁴	Ground

MACOM recommends connecting unused package pins to ground.

4. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

* Restrictions on Hazardous Substances, European Union Directive 2011/65/EU.

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Electrical Specifications: T_A = +25°C

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Forward Voltage	+50 mA DC	V	0.7	0.9	1.1
Reverse Leakage Current	-100 V DC	nA	_	- 20	-1000
Total Capacitance ⁵	-50 V @ 1 MHz	pF	_	0.24	0.35
Series Resistance ⁶	+10 mA @ 1 GHz	Ω		1.9	2.6
Parallel Resistance ⁶	-Vdc = -40 V, @ 100 MHz	KΩ		500	
Minority Carrier Lifetime	+If = 10 mA / -Ir = -6 mA (50% Control Voltage, 90% Output Voltage)	μs		1.0	2.0
CW Thermal Resistance (Infinite Heat Sink at Thermal Ground Plane)	l High = 4 A, I low = 10 mA @ 10 kHz	°C/W		45	
Power Dissipation ^{7,8} (Infinite Heat Sink at Thermal Ground Plane)	+lf = 50 mA @ 1 GHz	W		3.3	_
Insertion Loss	F = 1 GHz, -Vdc = -10 V	dB		0.1	
Isolation	F = 1 GHz, +I bias = +10 mA	dB	21	23	—

5. Ct (Total Capacitance) = CJ (Junction Capacitance) + Cp (Parasitic Package Capacitance).

6. Rs and Rp are measured on an HP4291A Impedance Analyzer.

7. De-rate power dissipation linearly by -22.2 mW/°C to 0 W @ +175°C: Pd (T) = Pd (+25°C) - ΔP = Pd (+25°) - (22.2 mV/°C) (ΔT).

8. PD = Δ Tj / Θ or PD=(IF + IRF) 2 (Rs), where IF is the forward bias DC current and IRF is the forward bias RMS RF current.

Absolute Maximum Ratings^{9,10}

Parameter	Absolute Maximum
DC Forward Voltage @ +250 mA	1.2 V
DC Forward Current	250 mA
DC Reverse Voltage	-100V
Junction Temperature	+175°C
Operating Temperature	-65°C to +125°C
Storage Temperature	-65°C to +150°C

9. Exceeding any one or combination of these limits may cause permanent damage to this device.

10. MACOM does not recommend sustained operation near these survivability limits.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

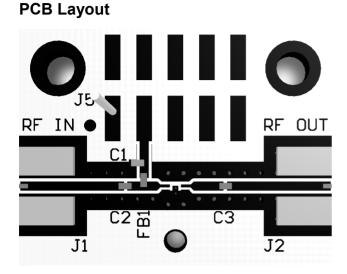
These devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1B devices.

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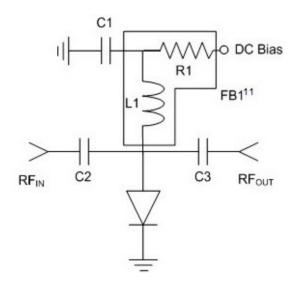


500 - 5000 MHz Parts List¹²

Part	Value	Case Style
C1	62 pF	0402
C2, C3	100 pF	0402
FB1	470 Ω @ 1 GHz	0402
R1	150 Ω	0402
L1	82 nH	0402

12. Max DC voltage with recommended components not to exceed 100 V.

PCB Schematic



11. R1 is not needed when using the recommended ferrite FB1.

Assembly Recommendations

Devices may be soldered using standard Pb60/Sn40, or RoHS compliant solders. Leads are plated NiPdAuAg to ensure an optimum solderable connection.

For recommended Sn/Pb and RoHS soldering profile See Application Note $\underline{\mathsf{M538}}$ on the MACOM website.

Cleanliness and Storage

These devices should be handled and stored in a clean environment. Ends of the device are NiPdAuAg plated for greater solderability. Exposure to high humidity (>80%) for extended periods may cause the surface to oxidize. Caution should be taken when storing devices for long periods.

General Handling

Device can be handled with tweezers or vacuum pickups and are suitable for use with automatic pick-and-place equipment.

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1000

100

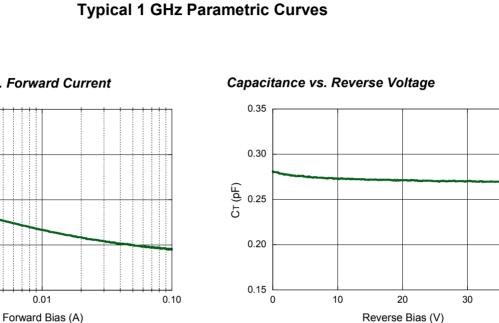
10

1

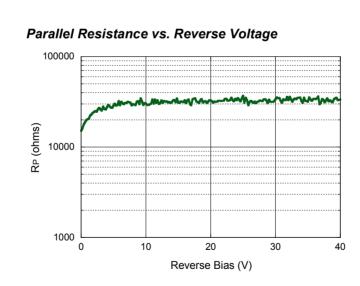
0.1

0.00

Rs (ohms)



Series Resistance vs. Forward Current



4

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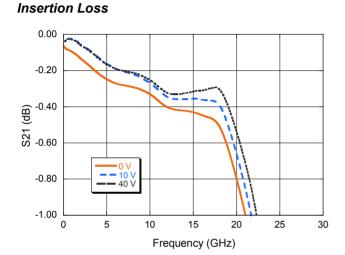
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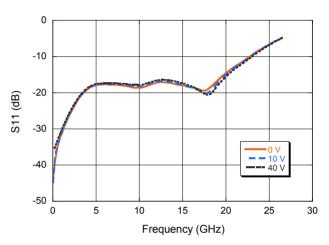
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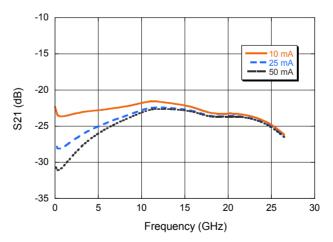
Typical RF Small Signal Performance Curves







Isolation



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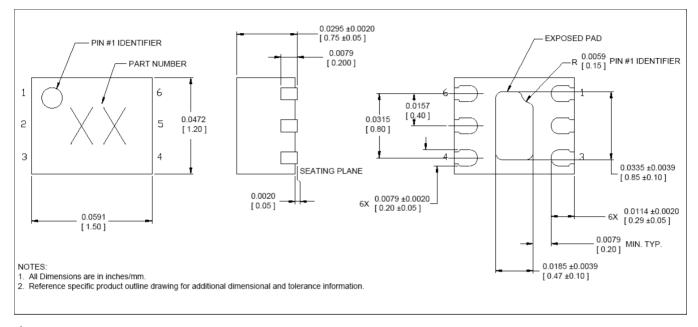
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Lead-Free 1.5 x 1.2 mm 6-Lead TDFN[†]



[†] Reference Application Note <u>S2083</u> for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements. Plating is NiPdAuAg.

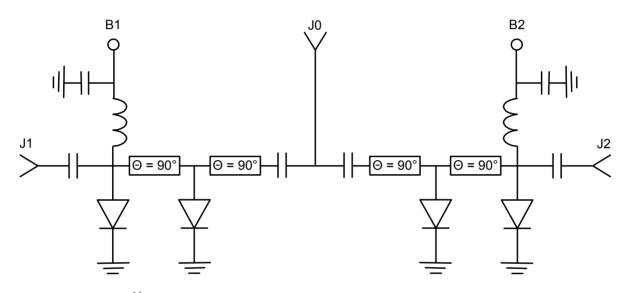


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Applications Section

Schematic of High Power SP2T Shunt Switch using MADP-011027-14150T PIN Diodes F = Octave Bandwidth from 1 to 18 GHz $P_{inc} = +40 dBm CW$ $P_{inc} = +50 dBm, 10 \,\mu s PW, 1\% Duty$



L = 11.807 / ($\epsilon eff^{\frac{1}{2}} + F + 4$) inches, $\theta = \beta + L = (2\pi / \lambda) + L = 90^{\circ}$

Frequency is in GHz, Eeff is Effective Dielectric Constant of Transmission Line Medium

RF State	B1 Bias	B2 Bias
J0-J1 Low Loss & J0-J2 Isolation	-50 V @ 0 mA	+1 V @ +20 mA
J0-J2 Low Loss & J0-J1 Isolation	+1 V @ +20 mA	-50 V @ 0 mA

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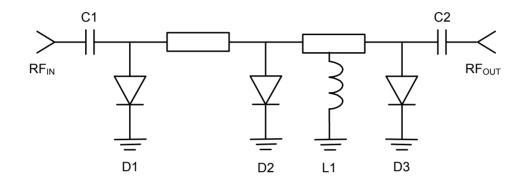


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Applications Section

Schematic of 3 Stage Limiter using MADP-011027-14150T F = 1000 - 8000 MHz $P_{inc} = +43 \text{ dBm CW}$ $P_{inc} = +50 \text{ dBm}, 10 \mu \text{s P.W.}, 1\% \text{ Duty}$



Part	PN	Case Style	Description	Quantity
D1	MADP-011027-14150T	ODS-1415	Input PIN Diode	1
D2	MADL-011023-14150T	ODS-1415	2nd Stage PIN Diode	1
D3	MADL-011023-14150T	ODS-1415	3rd Stage PIN Diode	1
L1	33 nH	0402	RF Choke / DC Return	1
C1	27 pF	0402	DC Block	1
C2	27 pF	0402	DC Block	1

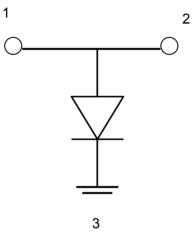
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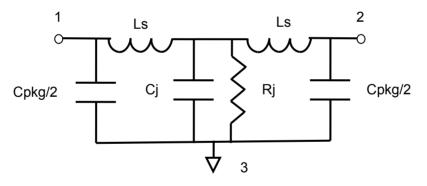


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Microwave Model of MADP-011027-14150T





Rj = Rs (Forward Bias Current) Rj = Rp (Reverse Bias Voltage)

Parameter	Value
$C_{package}$	0.16 pF
L bond = Ls	0.8 nH
Rs	0.9 Ω
Rp	5 kΩ

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